**TEXAS INSTRUMENTS**

TPS7A16-Q1 具有使能引脚和电源正常状态指示输出的 60V、5µA I$_Q$、100mA 低压降稳压器

1 特性

- 符合面向汽车应用的 AEC-Q100 标准：
  - 温度等级 1：–40°C 至 +125°C，T$_A$
  - 器件 HBM ESD 分类等级 H2
  - 器件 CDM ESD 分类等级 C3B
- 宽输入电压范围：3V 至 60V
- 超低静态电流：5µA
- 关断时静态电流为：1µA
- 输出电流：100mA
- 低压降：20 mA 时为 60 mV
- 精度：2%
- 可提供：
  - 固定输出电压：3.3V 和 5V
  - 可调节输出电压：大约 1.2 至 18.5V
- 具有可编程延迟的电源正常状态指示功能
- 电流限制和热关断保护
- 与陶瓷输出电容器一起工作时保持稳定：
  ≥ 2.2µF
- 功能安全型
  - 可提供用于功能安全系统设计的文档
- 封装：带散热焊盘的高热性能、8 引脚 HVSSOP 封装

2 应用

- 紧急呼叫 (eCall)
- 电池管理系统 (BMS)
- 车载充电器 (OBC) 和无线充电器
- 直流/直流转换器
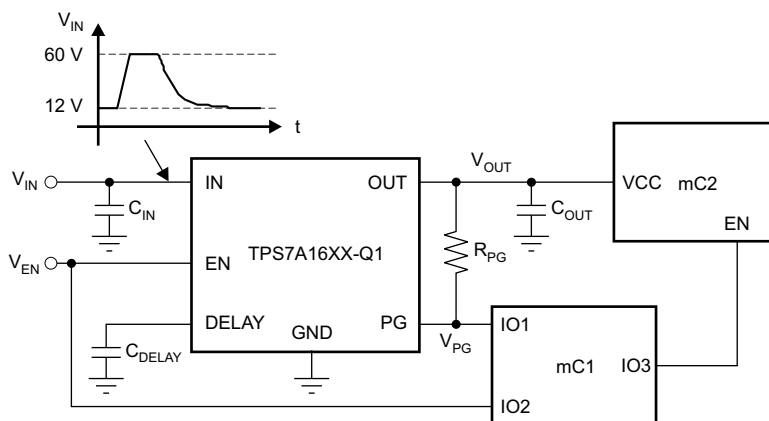
3 说明

TPS7A16-Q1 超低功耗、低压降 (LDO) 稳压器具有超低静态电流、高输入电压以及微型高热性能封装等诸多优势。

TPS7A16-Q1 设计用于连续或者断续（备用电源）电池供电的应用，在此类应用中，超低的静态电流对于延长系统电池的寿命十分关键。

TPS7A16A-Q1 提供了一个与标准 CMOS 逻辑兼容的使能引脚 (EN)，以及一个具有用户可编程延迟的集成开漏高电平有效电源正常状态指示输出 (PG) 引脚。这些引脚用于基于微控制器、由电池供电且需要电源轨排序的应用。

此外，TPS7A16-Q1 设计用于为多节电池解决方案（从多节电池电动工具组到汽车应用）生成低电压电源，不仅能够提供一个稳压良好的电压轨，还能够承受瞬态电压并在电压瞬态期间保持稳压状态。这些特性意味着电涌保护电路更加简单且更为经济高效。

封装信息

器件型号	封装[1]	封装尺寸（标称值）
TPS7A16-Q1	DGN（HVSSOP，8）	3.00mm × 3.00mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

典型应用原理图

English Data Sheet: SBVS188

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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision D (August 2014) to Revision E (May 2023)	Page
• 向*特性* 部分添加了 *功能安全* 和*封装* 要点	1
• 添加了指向*应用* 部分的链接	1
• Changed pinout drawing to show pin 2 as FB/NC instead of FB/DNC and changed description of pin 2 in *Pin Functions* table	3

Changes from Revision C (August 2014) to Revision D (May 2016)	Page
• 更改了数据表标题	1
• Changed *Handling Ratings* table to *ESD Ratings*; moved storage temperature to *Absolute Maximum Ratings*	4
• Changed maximum EN pin voltage and added a row for EN slew rate	5
• Changed UNIT for accuracy on V_{OUT}	6
• Changed *Ground current* to *Quiescent current*	6
• Changed 图 6-2	7
• Changed caption of 图 6-3	7
• Changed and added text in *Enable (EN)* section	10
• Moved three paragraphs of text from *Layout Examples* to *Layout Guidelines*	18

Product Folder Links: *TPS7A16-Q1*

English Data Sheet: SBVS188

5 Pin Configuration and Functions
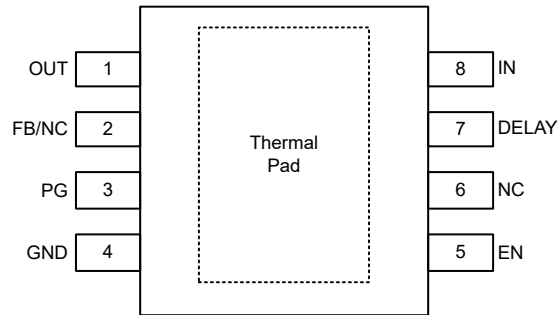
NC – No internal connection

图 5-1. DGN Package, 8-Pin HVSSOP With Exposed Thermal Pad (Top View)

表 5-1. Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
DELAY	7	O	Delay pin. Connect a capacitor to GND to adjust the PG delay time; leave open if the reset function is not needed.
EN	5	I	Enable pin. This pin turns the regulator on or off. If $V_{EN} \geq V_{EN\_HI}$, the regulator is enabled. If $V_{EN} \leq V_{EN\_LO}$, the regulator is disabled. If not used, the EN pin can be connected to IN. Make sure that $V_{EN} \leq V_{IN}$ at all times.
FB/NC	2	I	This pin is a feedback pin when using an external resistor divider or an NC pin when using the device with a fixed output voltage. When using the adjustable device, this pin must be connected through a resistor divider to the output for the device to function. If using a fixed output this pin can either be left floating or connected to GND.
GND	4	—	Ground pin
IN	8	I	Regulator input supply pin. A capacitor > 0.1 μF must be tied from this pin to ground to assure stability. Connect a 10-μF ceramic capacitor from IN to GND (as close to the device as possible) to reduce circuit sensitivity to printed-circuit-board (PCB) layout, especially when long input tracer or high source impedances are encountered.
NC	6	—	This pin can be left open or tied to any voltage between GND and IN.
OUT	1	O	Regulator output pin. A capacitor > 2.2 μF must be tied from this pin to ground to assure stability. Connect a 10-μF ceramic capacitor from OUT to GND (as close to the device as possible) to maximize ac performance.
PG	3	O	Power-good pin. Open-collector output; leave open or connect to GND if the power-good function is not needed.
Thermal pad	—		Solder to printed circuit board (PCB) to enhance thermal performance. Although the thermal pad can be left floating, connecting the thermal pad to the GND plane is highly recommended.

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Product Folder Links: TPS7A16-Q1

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6 Specifications

6.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted) [1]

		MIN	MAX	UNIT
Voltage	IN pin to GND pin	−0.3	62	V
	OUT pin to GND pin	−0.3	20	
	OUT pin to IN pin	−62	0.3	
	FB pin to GND pin	−0.3	3	
	FB pin to IN pin	−62	0.3	
	EN pin to IN pin	−62	0.3	
	EN pin to GND pin	−0.3	62	
	PG pin to GND pin	−0.3	5.5	
	DELAY pin to GND pin	−0.3	5.5	
Current	Peak output	Internally limited		
Temperature	Operating virtual junction, T_J, absolute maximum range[2]	−40	150	°C
	Storage temperature range	−65	150	

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Permanent damage does not occur to the part operating within this range, though electrical performance is not guaranteed outside the operating ambient temperature range.

6.2 ESD Ratings

			MIN	MAX	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per AEC Q100-002[1]	−2	2	kV
		Charged device model (CDM), per AEC Q100-011 — Corner pins (OUT, GND, IN, and EN)	−750	750	V
		Charged device model (CDM), per AEC Q100-011 — Other pins	−500	500	

(1) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{IN}	Unregulated input	3		60	V
V_{OUT}	Regulated output	1.2		18	V
EN	Voltage	0		V_{IN}	V
	Slew rate, voltage ramp-up			1.5	V/μs
DELAY	Delay pin voltage	0		5	V
PG	Power-good pin voltage	0		5	V
T_J	Operating junction temperature range	−40		150	°C

6.4 Thermal Information

THERMAL METRIC[1]		TPS7A16-Q1	UNIT
		DGN (HVSSOP)	
		8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	66.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case(top) thermal resistance	45.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	34.6	°C/W
ψ_{JT}	Junction-to-top characterization parameter	1.9	°C/W
ψ_{JB}	Junction-to-board characterization parameter	34.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case(bottom) thermal resistance	14.9	°C/W

(1)   For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application note.

Product Folder Links: *TPS7A16-Q1*

English Data Sheet: *SBVS188*

6.5 Electrical Characteristics

at T_A= –40°C to +125°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or V_{IN} = 3 V (whichever is greater), V_{EN} = V_{IN}, I_{OUT} = 10 μA, C_{IN} = 1 μF, C_{OUT} = 2.2 μF, and FB tied to OUT (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IN}	Input voltage range		3		60	V
V_{REF}	Internal reference	T_A = 25°C, V_{FB} = V_{REF}, V_{IN} = 3 V, I_{OUT} = 10 μA	1.169	1.193	1.217	V
V_{UVLO}	Undervoltage lockout threshold			2.7		V
V_{OUT}	Output voltage range	V_{IN} ⩾ $V_{OUT(NOM)}$ + 0.5 V	V_{REF}		18.5	V
	Nominal accuracy	T_A = 25°C, V_{IN} = 3 V, I_{OUT} = 10 μA	–2%		2%	
	Overall accuracy	$V_{OUT(NOM)}$ + 0.5 V ⩽ V_{IN} ⩽ 60 V[1] 10 μA ⩽ I_{OUT} ⩽ 100 mA	–2%		2%	
$\Delta V_{O(\Delta VI)}$	Line regulation	3 V ⩽ V_{IN} ⩽ 60 V			±1	%V_{OUT}
$\Delta V_{O(\Delta IO)}$	Load regulation	10 μA ⩽ I_{OUT} ⩽ 100 mA			±1	%V_{OUT}
V_{DO}	Dropout voltage	V_{IN} = 4.5 V, $V_{OUT(NOM)}$ = 5 V, I_{OUT} = 20 mA		60		mV
		V_{IN} = 4.5 V, $V_{OUT(NOM)}$ = 5 V, I_{OUT} = 100 mA		265	500	mV
I_{LIM}	Current limit	V_{OUT} = 90% $V_{OUT(NOM)}$, V_{IN} = 3.0 V	101	225	400	mA
I_Q	Quiescent current	3 V ⩽ V_{IN} ⩽ 60 V, I_{OUT} = 10 μA		5	15	μA
		I_{OUT} = 100 mA		5		μA
I_{SHDN}	Shutdown supply current	V_{EN} = 0.4 V		0.59	5.0	μA
I_{FB}	Feedback current[2]		–1	0.0	1	μA
I_{EN}	Enable current	3 V ⩽ V_{IN} ⩽ 12 V, V_{IN} = V_{EN}	–1	0.01	1	μA
V_{EN_HI}	Enable high-level voltage		1.2			V
V_{EN_LO}	Enable low- level voltage				0.3	V
V_{IT}	PG trip threshold	OUT pin floating, V_{FB} increasing, V_{IN} ⩾ V_{IN_MIN}	85		95	%V_{OUT}
		OUT pin floating, V_{FB} decreasing, V_{IN} ⩾ V_{IN_MIN}	83		93	%V_{OUT}
V_{HYS}	PG trip hysteresis			2.3	4	%V_{OUT}
$V_{PG, LO}$	PG output low voltage	OUT pin floating, V_{FB} = 80% V_{REF}, I_{PG}= 1mA			0.4	V
$I_{PG, LKG}$	PG leakage current	V_{PG}= $V_{OUT(NOM)}$	–1		1	μA
I_{DELAY}	DELAY pin current			1	2	μA
PSRR	Power-supply rejection ratio	V_{IN} = 3 V, $V_{OUT(NOM)}$ = V_{REF}, C_{OUT} = 10 μF, f = 100 Hz		50		dB
T_{SD}	Thermal shutdown temperature	Shutdown, temperature increasing		170		°C
		Reset, temperature decreasing		150		°C
T_A	Operating ambient temperature range		–40		125	°C

(1)   Maximum input voltage is limited to 24 V because of the package power dissipation limitations at full load (P ≈ (V_{IN} – V_{OUT}) × I_{OUT} = (24 V – V_{REF}) × 50 mA ≈ 1.14 W). The device is capable of sourcing a maximum current of 50 mA at higher input voltages as long as the power dissipated is within the thermal limits of the package plus any external heat sinking.

(2) I_{FB} > 0 flows out of the device.

6.6 Typical Characteristics

at T_A = – 40°C to +125°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or V_{IN} = 3 V (whichever is greater), V_{EN} = V_{IN}, I_{OUT} = 10 μA, C_{IN} = 1 μF, C_{OUT} = 2.2 μF, and FB tied to OUT (unless otherwise noted)
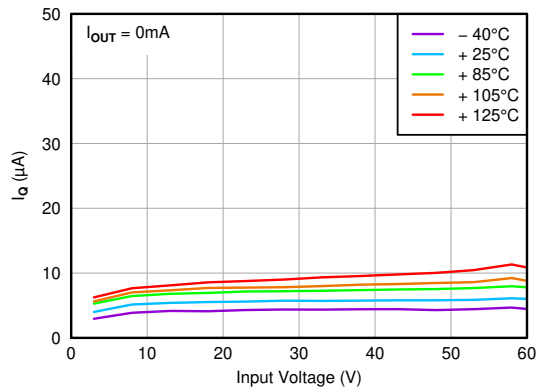

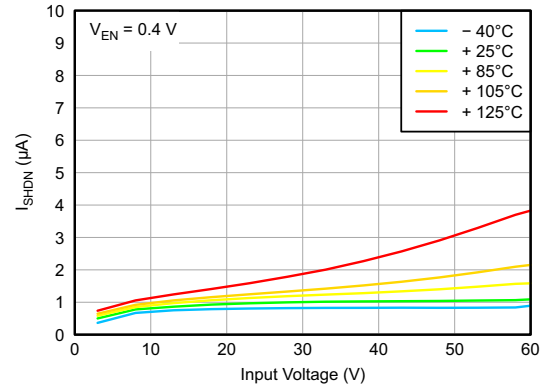**图 6-1. Quiescent Current vs Input Voltage**

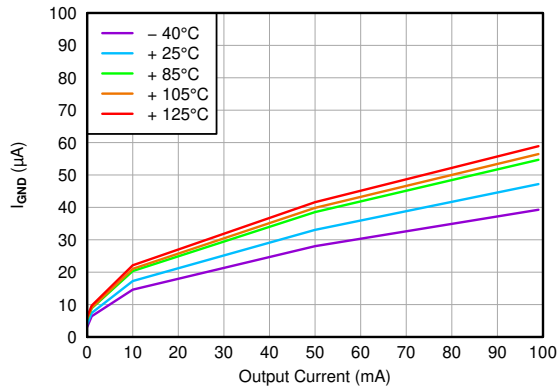**图 6-2. Shutdown Current vs Input Voltage**

图 6-3. Quiescent Current vs Output Current
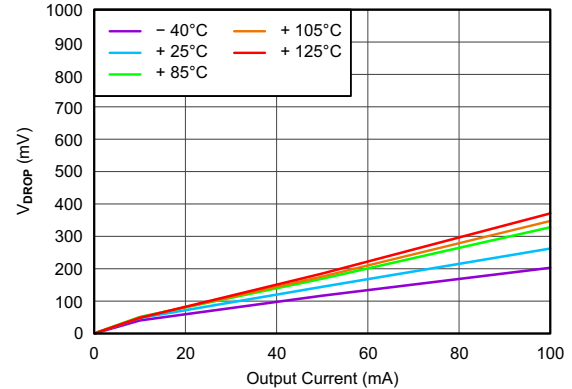

图 6-4. Dropout Voltage vs Output Current

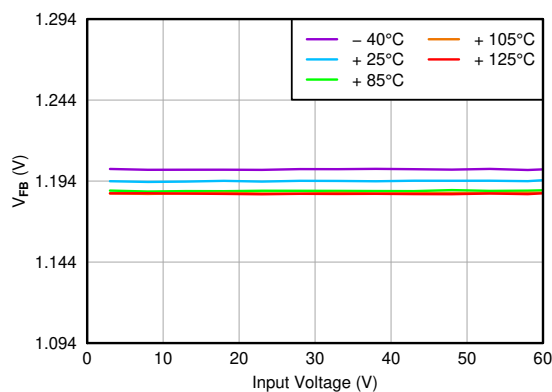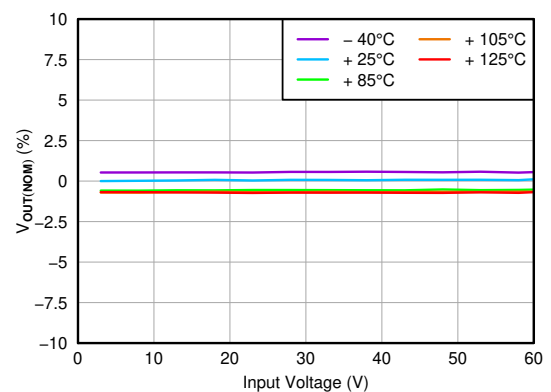**图 6-5. Feedback Voltage vs Input Voltage**

图 6-6. Line Regulation

Product Folder Links: *TPS7A16-Q1*

English Data Sheet: *SBVS188*

6.6 Typical Characteristics (continued)

at T_A = – 40°C to +125°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or V_{IN} = 3 V (whichever is greater), V_{EN} = V_{IN}, I_{OUT} = 10 μA, C_{IN} = 1 μF, C_{OUT} = 2.2 μF, and FB tied to OUT (unless otherwise noted)
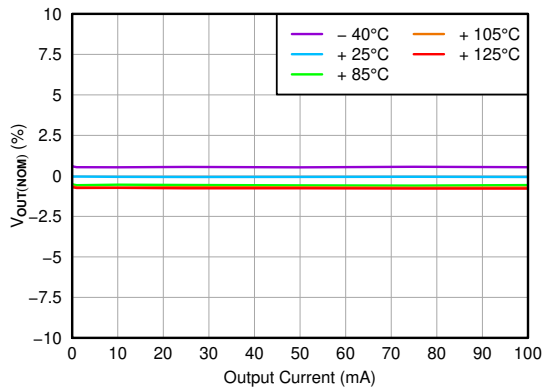
图 6-7. Load Regulation
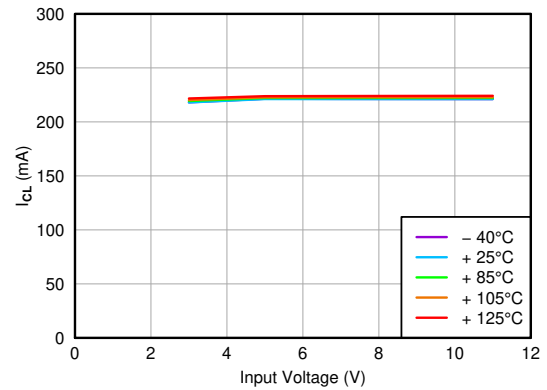
图 6-8. Current Limit vs Input Voltage
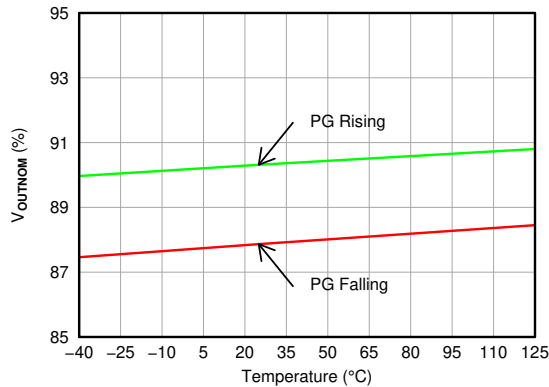
图 6-9. Power-Good Threshold Voltage vs Temperature
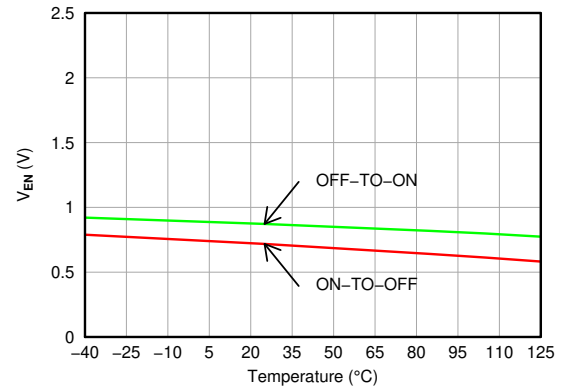
图 6-10. Enable Threshold Voltage vs Temperature
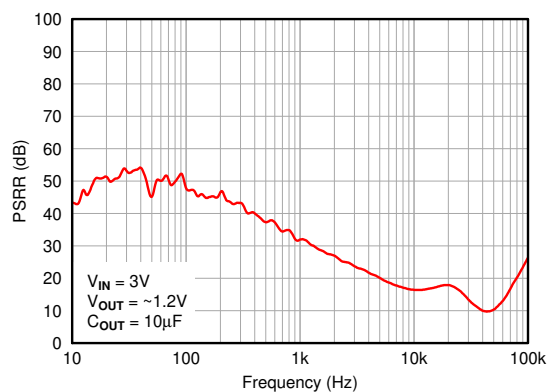
图 6-11. Power-Supply Rejection Ratio
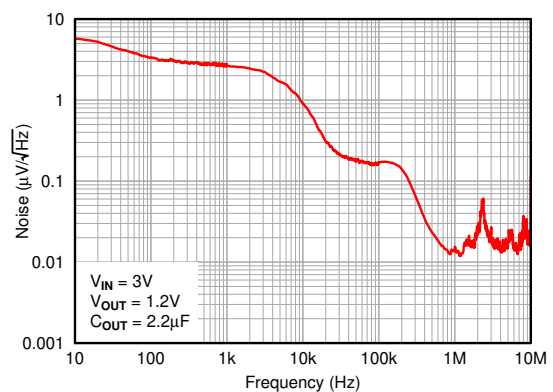
图 6-12. Output Spectral Noise Density

Product Folder Links: *TPS7A16-Q1*

English Data Sheet: SBVS188

6.6 Typical Characteristics (continued)

at $T_A = -40°C$ to $+125°C$, $V_{IN} = V_{OUT(NOM)} + 0.5$ V or $V_{IN} = 3$ V (whichever is greater), $V_{EN} = V_{IN}$, $I_{OUT} = 10\ \mu A$, $C_{IN} = 1\ \mu F$, $C_{OUT} = 2.2\ \mu F$, and FB tied to OUT (unless otherwise noted)

V_{IN} (2 V/div)

C_{DELAY} = 1 nF

C_{DELAY} = 10 nF

V_{PG} (2 V/div)

C_{DELAY} = 0 nF

$V_{IN} = 1$ V → 6.5 V
$I_{OUT} = 1$ mA
$C_{OUT} = 10\ \mu F$
$C_{FF} = 0$ nF

V_{OUT} (1 V/div)

OUT_DC

Time (5 ms/div)

图 6-13. Power-Good Delay

Product Folder Links: *TPS7A16-Q1*

English Data Sheet: *SBVS188*

7 Detailed Description

7.1 Overview

The TPS7A16-Q1 is an ultra low power, low-dropout (LDO) voltage regulator that offers the benefits of ultra-low quiescent current, high input voltage, and miniaturized, high thermal-performance packaging. The TPS7A16-Q1 also offers an enable pin (EN) and integrated open-drain, active-high, power-good output (PG) with a user-programmable delay.

7.2 Functional Block Diagram

7.3 Feature Description

7.3.1 Enable (EN)

The enable pin is a high-voltage-tolerant pin. A high input on EN actives the device and turns on the regulator. For self-bias applications, connect this input to the V_{IN} pin. Make sure that $V_{EN} \leqslant V_{IN}$ at all times.

When the enable signal is PWM pulses, the slew rate of the rising and falling edges must be less than 1.5 V/µs. Adding a 0.1-µF capacitor from the EN pin to GND is recommended.

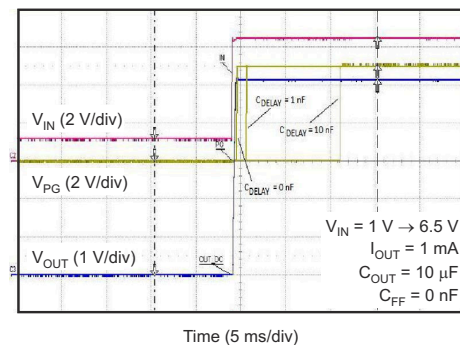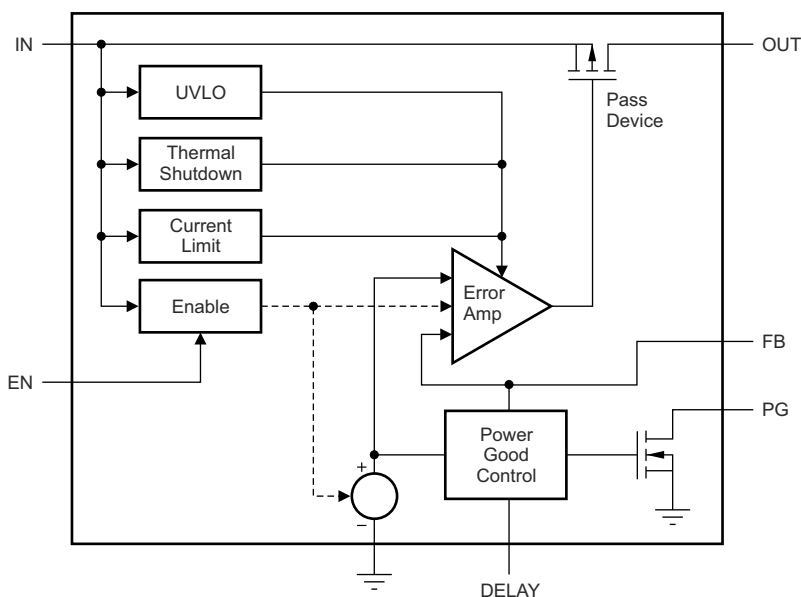### 7.3.2 Regulated Output (V_{OUT})

The V_{OUT} pin is the regulated output based on the required voltage. The output has current limitation. During initial power-up, the regulator has a soft-start incorporated to control the initial current through the pass transistor. In the event that the regulator drops out of regulation, the output tracks the input minus a drop based on the load current. When the input voltage drops below the undervoltage lockout (UVLO) threshold, the regulator shuts down until the input voltage recovers above the minimum start-up level.

7.3.3 PG Delay Timer (DELAY)

The power-good delay time (t_{DELAY}) is defined as the time period from when V_{OUT} exceeds the PG trip threshold voltage (V_{IT}) to when the PG output is high. This power-good delay time is set by an external capacitor (C_{DELAY}) connected from the DELAY pin to GND; this capacitor is charged from 0 V to approximately 1.8 V by the DELAY pin current (I_{DELAY}) when V_{OUT} exceeds the PG trip threshold (V_{IT}).

Product Folder Links: *TPS7A16-Q1*

7.4 Device Functional Modes

7.4.1 Power-Good

The power-good (PG) pin is an open-drain output and can be connected to any 5.5-V or lower rail through an external pullup resistor. When no C_{DELAY} is used, the PG output is high-impedance when V_{OUT} is greater than the PG trip threshold (V_{IT}). If V_{OUT} drops below V_{IT}, the open-drain output turns on and pulls the PG output low. If output voltage monitoring is not needed, the PG pin can be left floating or connected to GND.

To provide proper operation of the power-good feature, maintain $V_{IN} \geqslant 3$ V (V_{IN_MIN}).

7.4.2 Power-Good Delay and Delay Capacitor

The power-good delay time (t_{DELAY}) is defined as the time period from when V_{OUT} exceeds the PG trip threshold voltage (V_{IT}) to when the PG output is high. This power-good delay time is set by an external capacitor (C_{DELAY}) connected from the DELAY pin to GND; this capacitor is charged from 0 V to approximately 1.8 V by the DELAY pin current (I_{DELAY}) when V_{OUT} exceeds the PG trip threshold (V_{IT}).

When C_{DELAY} is used, the PG output is high-impedance when V_{OUT} exceeds V_{IT}, and V_{DELAY} exceeds V_{REF}.

The power-good delay time can be calculated using: $t_{DELAY} = (C_{DELAY} \times V_{REF}) / I_{DELAY}$. For example, when $C_{DELAY} = 10$ nF, the PG delay time is approximately 12 ms; that is, (10 nF × 1.193 V) / 1 μA = 11.93 ms.

Product Folder Links: TPS7A16-Q1

English Data Sheet: SBVS188

8 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客 户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

8.1 Application Information

The TPS7A16-Q1 ultra-low-power voltage regulator offers the benefit of ultra-low quiescent current, high input voltage, and miniaturized, high-thermal-performance packaging.

The TPS7A16-Q1 is designed for continuous or sporadic (power backup) battery-operated applications where ultra-low quiescent current is critical to extending system battery life.

8.2 Typical Applications

8.2.1 TPS7A1601-Q1 Circuit as an Adjustable Regulator

Where: $R_1 = R_2 \left(\dfrac{V_{OUT}}{V_{REF}} - 1 \right)$
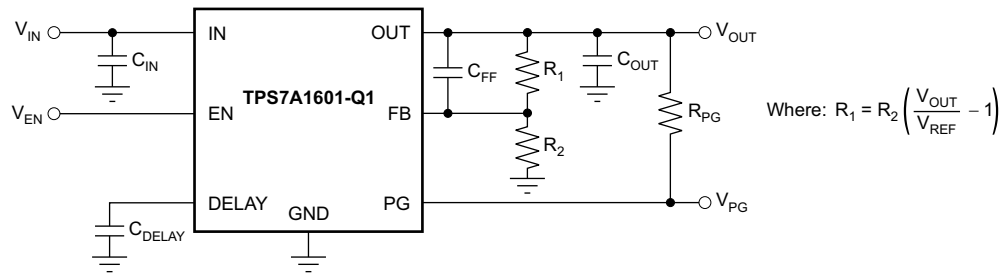
图 8-1. TPS7A1601-Q1 Circuit as an Adjustable Regulator Schematic

8.2.1.1 Design Requirements

表 8-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	5.5 V to 40 V
Output voltage	5 V
Output current rating	100 mA
Output capacitor range	2.2 µF to 100 µF
Delay capacitor range	100 pF to 100 nF

Product Folder Links: *TPS7A16-Q1*

English Data Sheet: *SBVS188*

8.2.1.2 Detailed Design Procedure

8.2.1.2.1 Adjustable Voltage Operation

The TPS7A1601-Q1 has an output voltage range from 1.194 V to 20 V. The nominal output of the device is set by two external resistors, as shown in 图 8-2:
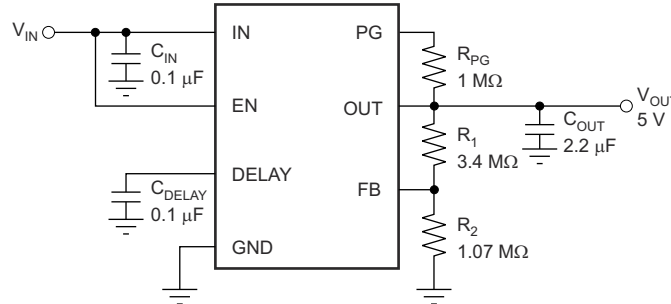

图 8-2. Adjustable Operation

R_1 and R_2 can be calculated for any output voltage range using the formula shown in 方程式 1:

$$R_1 = R_2 \left(\frac{V_{OUT}}{V_{REF}} - 1 \right)$$

(1)

8.2.1.2.2 Resistor Selection

Use resistors in the order of megaohms (MΩ) to keep the overall quiescent current of the system as low as possible (by making the current used by the resistor divider negligible compared to the quiescent current of the device).

If greater voltage accuracy is required, take into account the voltage offset contributions as a result of feedback current and use 0.1% tolerance resistors.

表 8-2 shows the resistor combination to achieve an output for a few of the most common rails using commercially available 0.1% tolerance resistors to maximize nominal voltage accuracy, while adhering to the formula shown in 方程式 1.

表 8-2. Selected Resistor Combinations

V_{OUT}	R_1	R_2	$V_{OUT}/(R_1 + R_2)$ « I_Q	NOMINAL ACCURACY
1.194 V	0 Ω	∞	0 μA	±2%
1.8 V	1.18 MΩ	2.32 MΩ	514 nA	±(2% + 0.14%)
2..5 V	1.5 MΩ	1.37 MΩ	871 nA	±(2% + 0.16%)
3.3 V	2 MΩ	1.13 MΩ	1056 nA	±(2% + 0.35%)
5 V	3.4 MΩ	1.07 MΩ	1115 nA	±(2% + 0.39%)
10 V	7.87 MΩ	1.07 MΩ	1115 nA	±(2% + 0.42%)
12 V	14.3 MΩ	1.58 MΩ	755 nA	±(2% + 0.18%)
15 V	42.2 MΩ	3.65 MΩ	327 nA	±(2% + 0.19%)
18 V	16.2 MΩ	1.15 MΩ	1038 nA	±(2% + 0.26%)

Close attention must be paid to board contamination when using high-value resistors; board contaminants can significantly impact voltage accuracy. If board cleaning measures cannot be ensured, consider using a fixed-voltage version of the TPS7A16 or using resistors in the order of hundreds or tens of kiloohms (kΩ).

Submit Document Feedback   13

Product Folder Links: *TPS7A16-Q1*

English Data Sheet: SBVS188

8.2.1.2.3 Capacitor Recommendations

Use low equivalent-series-resistance (ESR) capacitors for the input, output, and feed-forward capacitors. Ceramic capacitors with X7R and X5R dielectrics are preferred. These dielectrics offer more stable characteristics. Ceramic X7R capacitors offer improved overtemperature performance, whereas ceramic X5R capacitors are the most cost-effective and are available in higher values.

However, high-ESR capacitors can degrade PSRR.

8.2.1.2.4 Input and Output Capacitor Requirements

The TPS7A16-Q1 ultra-low-power, high-voltage linear regulators achieve stability with a minimum input capacitance of 0.1 µF and output capacitance of 2.2 µF; however, use a 10-µF ceramic capacitor to maximize ac performance.

8.2.1.2.5 Feed-Forward Capacitor (Only for Adjustable Version)

Although a feed-forward capacitor (C_{FF}) from OUT to FB is not needed to achieve stability, using a 0.01-µF feed-forward capacitor to maximizes ac performance.

8.2.1.2.6 Transient Response

As with any regulator, increasing the size of the output capacitor reduces over- and undershoot magnitude but increases the duration of the transient response.
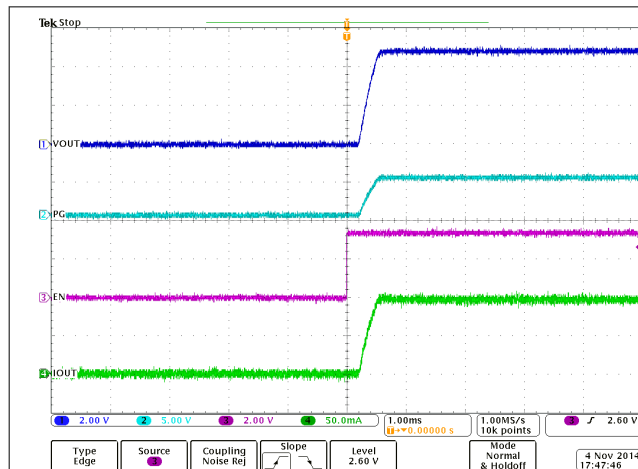
8.2.1.3 Application Curves

图 8-3. CH1 is VOUT, CH2 is PG, CH4 is Iout, VIN is 12 V and Ready Before EN
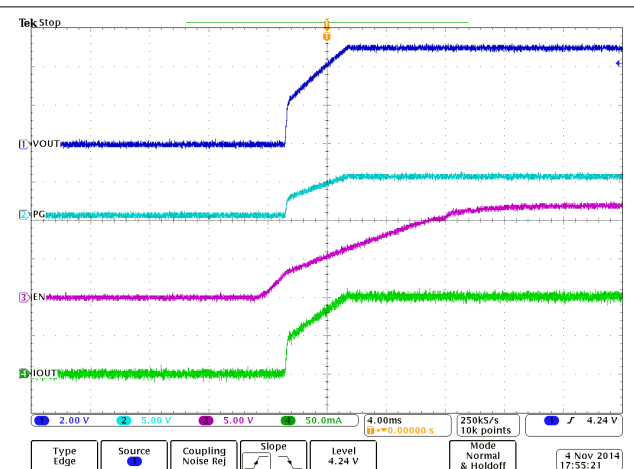
图 8-4. CH1 is VOUT, CH2 is PG, CH3 is EN, CH4 is Iout, VIN is 12 V Connected to EN

Product Folder Links: *TPS7A16-Q1*

English Data Sheet: *SBVS188*

8.2.2 Automotive Applications

The TPS7A16-Q1 maximum input voltage of 60 V makes the device designed for use in automotive applications where high-voltage transients are present.

Events such as load-dump overvoltage (where the battery is disconnected while the alternator is providing current to a load) can cause voltage spikes from 25 V to 60 V. To prevent any damage to sensitive circuitry, local transient voltage suppressors can be used to cap voltage spikes to lower, more manageable voltages.

The TPS7A16-Q1 can be used to simplify and lower costs in such cases. The very high voltage range allows this regulator not only to withstand the voltages coming out of these local transient voltage suppressors, but even replace them, thus lowering system cost and complexity.
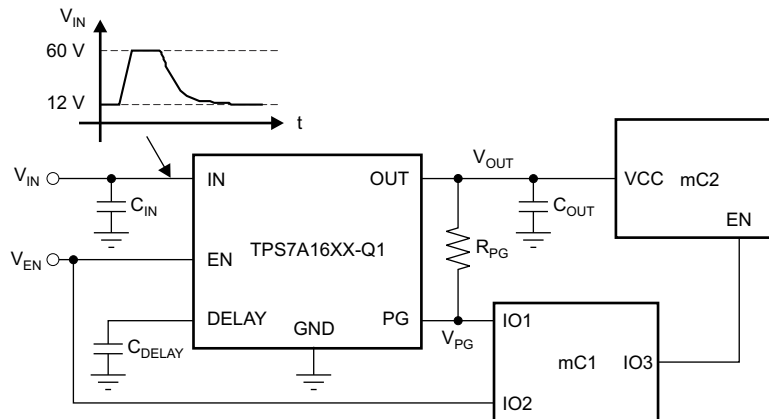
图 **8-5. Low-Power Microcontroller Rail Sequencing in Automotive Applications Subjected to Load-Dump Transients**

8.2.2.1 Design Requirements

表 **8-3. Design Parameters**

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	5.5 V to 60 V
Output voltage	5 V
Output current rating	100 mA
Output capacitor range	2.2 µF to 100 µF
Delay capacitor range	100 pF to 100 nF

8.2.2.2 Detailed Design Procedure

See the *Capacitor Recommendations* and *Input and Output Capacitor Requirements* sections.

8.2.2.2.1 Device Recommendations

The output is fixed, so choose the TPS7A1650-Q1.

8.2.2.3 Application Curves

See 图 8-3 and 图 8-4.

Product Folder Links: *TPS7A16-Q1*

English Data Sheet: SBVS188

8.2.3 Multicell Battery Packs

Currently, battery packs can employ up to a dozen cells in series that, when fully charged, can have voltages of up to 55 V. Internal circuitry in these battery packs is used to prevent overcurrent and overvoltage conditions that can degrade battery life or even pose a safety risk; this internal circuitry is often managed by a low-power microcontroller, such as TI's MSP430™. See the overview for microcontrollers (MCU) for more information.

The microcontroller continuously monitors the battery, whether the battery is in use or not. Although this microcontroller can be powered by an intermediate voltage taken from the multicell array, this approach unbalances the battery pack, degrading the battery life or adding cost to implement more complex cell-balancing topologies.

The best approach to power this microcontroller is to regulate down the voltage from the entire array to discharge every cell equally and prevent any balancing issues. This approach reduces system complexity and cost.

The TPS7A16-Q1 can be used for this application because this device can handle very high voltages (from the entire multicell array) and has very low quiescent current (to maximize battery life).
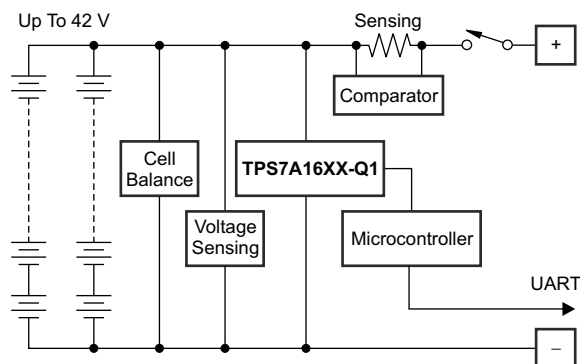
图 8-6. Protection Based on Low-Power Microcontroller Power From Multicell Battery Packs

8.2.3.1 Design Requirements

表 8-4. Device Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	5.5 V to 55 V
Output voltage	5 V
Output current rating	100 mA
Output capacitor range	2.2 µF to 100 µF
Delay capacitor range	100 pF to 100 nF

8.2.3.2 Detailed Design Procedure

See the *Device Recommendations*, *Capacitor Recommendations*, and *Input and Output Capacitor Requirements* sections.

8.2.3.3 Application Curves

See 图 8-3 and 图 8-4.

8.2.4 Battery-Operated Power Tools

High-voltage multicell battery packs support high-power applications (such as power tools) with high current drain when in use, highly intermittent use cycles, and physical separation between battery and motor.

In these applications, a microcontroller or microprocessor controls the motor. This microcontroller must be powered with a low-voltage rail coming from the high-voltage, multicell battery pack; as mentioned previously, powering this microcontroller or microprocessor from an intermediate voltage from the multicell array causes battery-pack life degradation or added system complexity because of cell balancing issues. In addition, this microcontroller or microprocessor must be protected from the high-voltage transients because of the motor inductance.

The TPS7A16-Q1 can be used to power the motor-controlled microcontroller or microprocessor; the device low quiescent current maximizes battery shelf life, and very high-voltage capabilities simplify system complexity by replacing voltage suppression filters, thus lowering system cost.
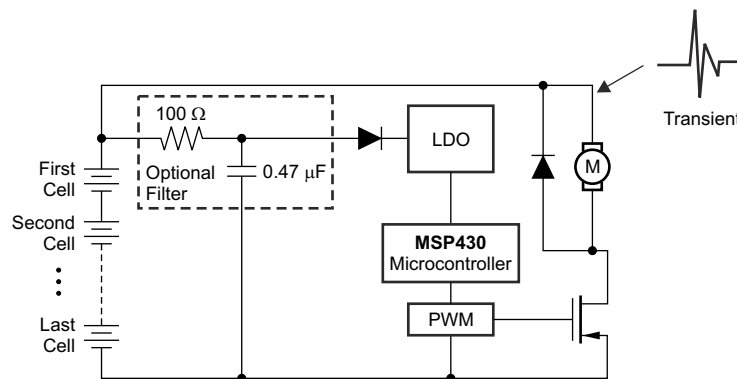
图 8-7. Low Power Microcontroller Power From Multicell Battery Packs in Power Tools

8.2.4.1 Design Requirements

表 8-5. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	5.5 V to 60 V
Output voltage	5 V
Output current rating	100 mA
Output capacitor range	2.2 μF to 100 μF
Delay capacitor range	100 pF to 100 nF

8.2.4.2 Detailed Design Procedure

See the *Device Recommendations*, *Capacitor Recommendations*, and *Input and Output Capacitor Requirements* sections.

8.2.4.3 Application Curves

See 图 8-3 and 图 8-4.

8.3 Power Supply Recommendations

Design of the device is for operation from an input voltage supply with a range between 3 V and 60 V. This input supply must be well regulated. The TPS7A16-Q1 ultra-low-power, high-voltage linear regulator achieves stability with a minimum input capacitance of 0.1 μF and output capacitance of 2.2 μF; however, the use of a 10-μF ceramic capacitor to maximize ac performance is highly recommended.

8.4 Layout

8.4.1 Layout Guidelines

To improve ac performance such as PSRR, output noise, and transient response, design the board with separate ground planes for IN and OUT, with each ground plane connected only at the GND pin of the device. In addition, the ground connection for the output capacitor must connect directly to the GND pin of the device.

Equivalent series inductance (ESL) and ESR must be minimized in order to maximize performance and provide stability. Every capacitor must be placed as close as possible to the device and on the same side of the PCB as the regulator.

Do not place any of the capacitors on the opposite side of the PCB from where the regulator is installed. Using vias and long traces is strongly discouraged because these components can impact system performance negatively and even cause instability.

If possible, and to provide the maximum performance denoted in this product data sheet, use the same layout pattern used for the TPS7A16-Q1 evaluation board, available at www.ti.com.

Layout is a critical part of good power-supply design. There are several signal paths that conduct fast-changing currents or voltages that can interact with stray inductance or parasitic capacitance to generate noise or degrade the power-supply performance. To help eliminate these problems, bypass the IN pin to ground with a low-ESR ceramic bypass capacitor with X5R or X7R dielectric.

Acceptable performance can possibly be obtained with alternative PCB layouts; however, the layout and schematic herein have been shown to produce good results and are meant as a guideline.

图 8-8 shows the schematic for the suggested layout. 图 8-9 and 图 8-10 show the top and bottom printed circuit board (PCB) layers for the suggested layout.

8.4.1.1 Additional Layout Considerations

The high impedance of the FB pin makes the regulator sensitive to parasitic capacitances that can couple undesirable signals from nearby components (especially from logic and digital devices, such as microcontrollers and microprocessors); these capacitively-coupled signals can produce undesirable output voltage transients. In these cases, use a fixed-voltage version of the TPS7A16-Q1, or isolate the FB node by flooding the local PCB area with ground-plane copper to minimize any undesirable signal coupling.

8.4.1.2 Power Dissipation

The ability to remove heat from the die is different for each package type, presenting different considerations in the PCB layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air. Using heavier copper increases the effectiveness of removing heat from the device. The addition of plated through-holes to heat dissipating layers also improves the heat sink effectiveness.

Power dissipation depends on input voltage and load conditions. Power dissipation (P_D) is equal to the product of the output current times the voltage drop across the output pass element, as shown in 方程式 2:

$$P_D = (V_{IN} - V_{OUT})\, I_{OUT}$$

(2)

8.4.1.3 Thermal Considerations

Thermal protection disables the output when the junction temperature rises to approximately 170°C, allowing the device to cool. When the junction temperature cools to approximately 150°C, the output circuitry is enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit can cycle on and off. This cycling limits the dissipation of the regulator, protecting the regulator from damage as a result of overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heat-spreading area. For reliable operation, limit junction temperature to a maximum of 125°C at the worst-case ambient temperature for a given application. To estimate the margin of safety in a complete design (including the copper heat-spreading area), increase the ambient temperature until the thermal protection is triggered; use

worst-case loads and signal conditions. For good reliability, thermal protection must trigger at least 45°C above the maximum expected ambient condition of the particular application. This configuration produces a worst-case junction temperature of 125°C at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS7A16-Q1 is designed to protect against overload conditions. This circuitry is not intended to replace proper heat sinking. Continuously running the TPS7A16-Q1 into thermal shutdown degrades device reliability.

8.4.2 Layout Examples
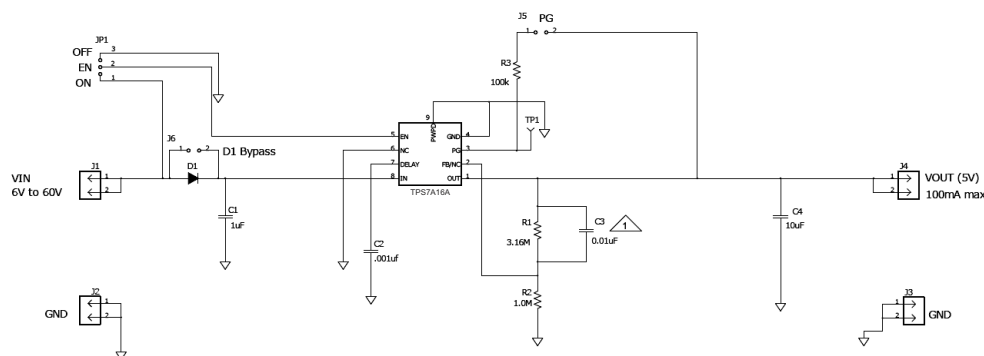
Copyright © 2017, Texas Instruments Incorporated

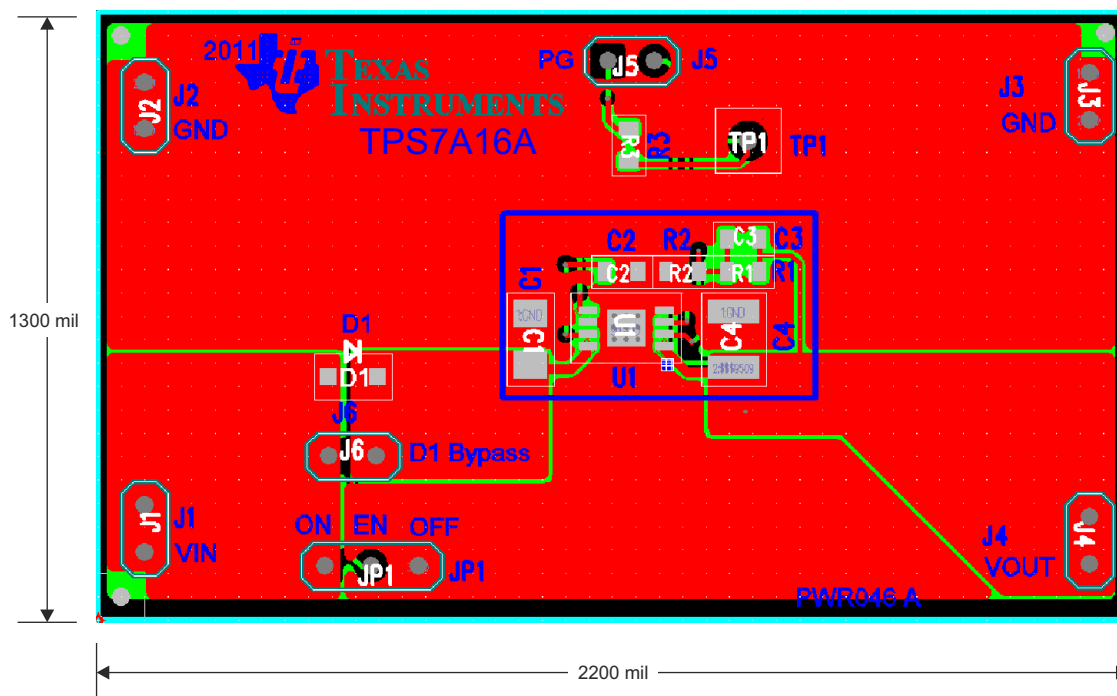图 8-8. **Schematic for Suggested Layout**

图 8-9. **Suggested Layout: Top Layer**

English Data Sheet: SBVS188
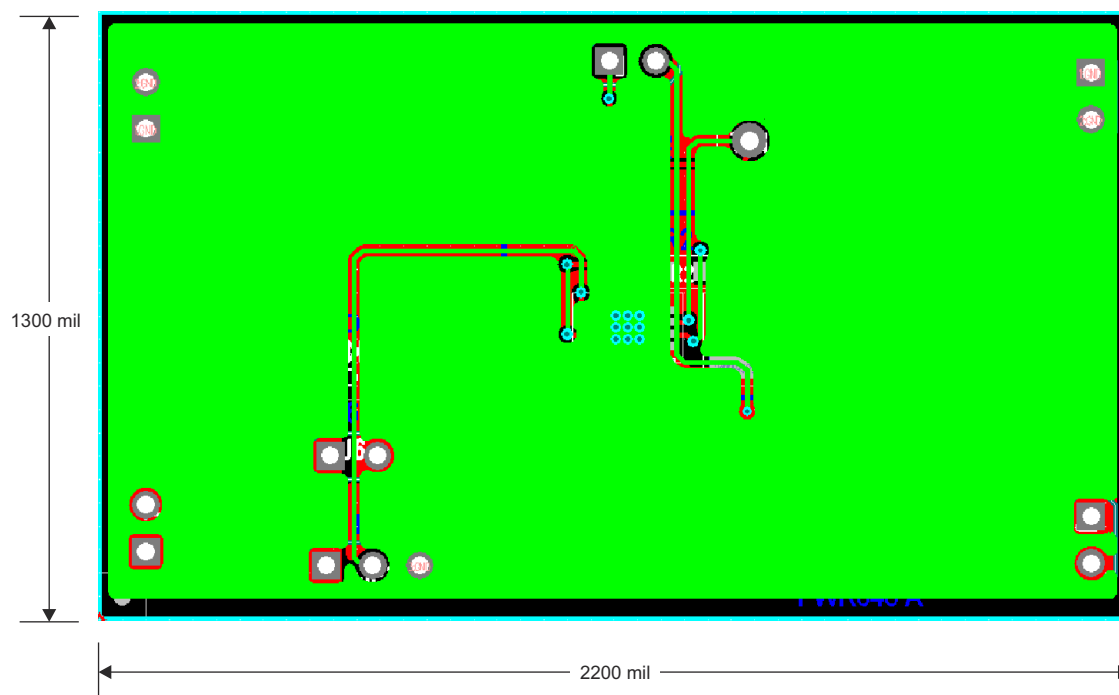
图 8-10. **Suggested Layout: Bottom Layer**

Product Folder Links: *TPS7A16-Q1*

English Data Sheet: SBVS188

9 Device and Documentation Support

9.1 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击*订阅更新*进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

9.2 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《使用条款》。

9.3 Trademarks

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所有商标均为其各自所有者的财产。

9.4 静电放电警告

静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

9.5 术语表

TI 术语表　　　　本术语表列出并解释了术语、首字母缩略词和定义。

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most-current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, see the left-hand navigation pane.

Product Folder Links: *TPS7A16-Q1*

English Data Sheet: SBVS188

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS7A1601QDGNRQ1	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	PXZQ
TPS7A1601QDGNRQ1.A	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	PXZQ
TPS7A1633QDGNRQ1	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PXYQ
TPS7A1633QDGNRQ1.A	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PXYQ
TPS7A1650QDGNRQ1	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	PYAQ
TPS7A1650QDGNRQ1.A	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	PYAQ

(1) Status: For more details on status, see our product life cycle.

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS7A16-Q1 :

- Catalog : TPS7A16

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7A1601QDGNRQ1	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS7A1633QDGNRQ1	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS7A1650QDGNRQ1	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

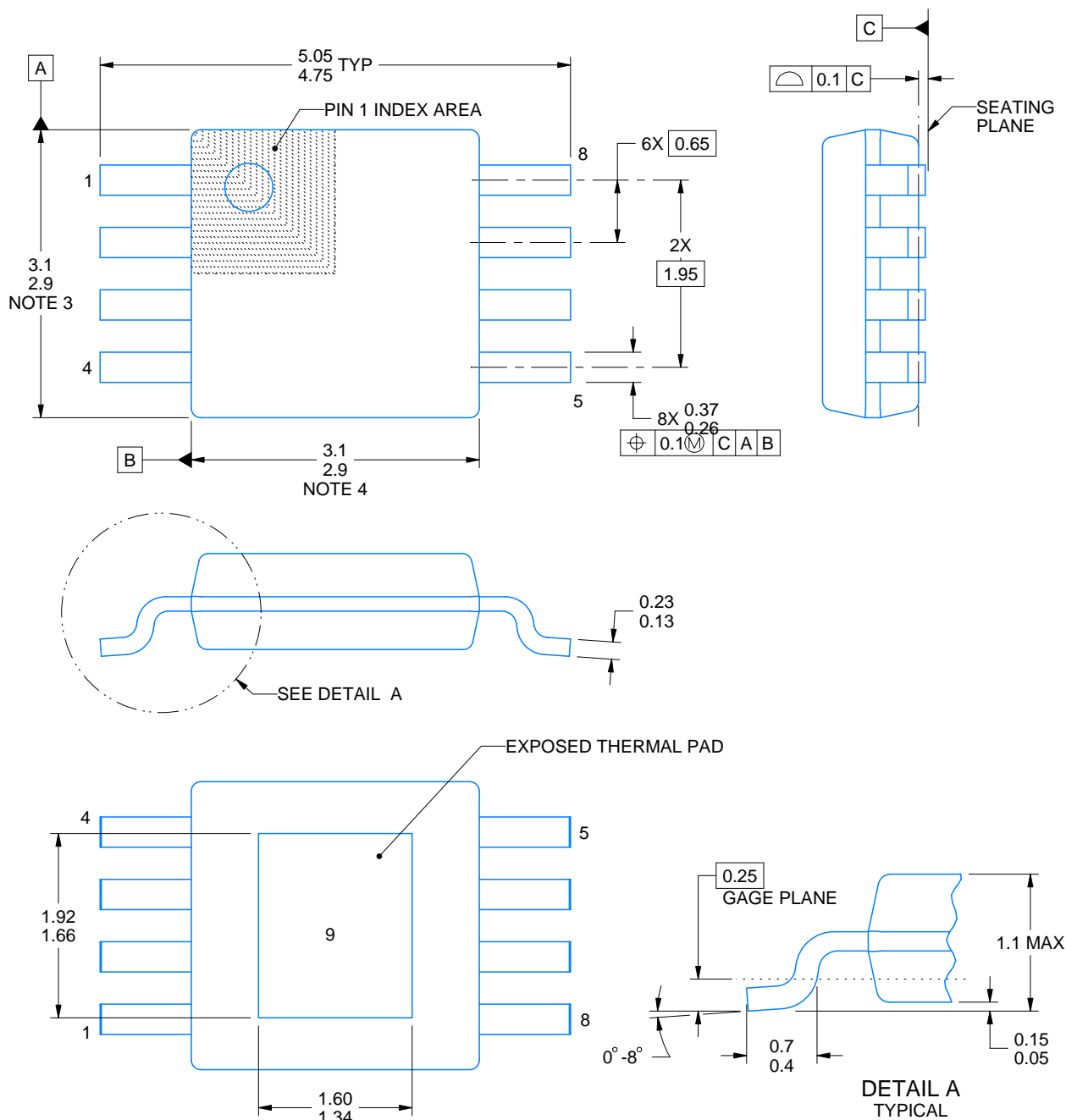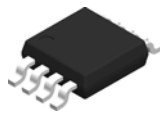| Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS7A1601QDGNRQ1	HVSSOP	DGN	8	2500	367.0	367.0	38.0
TPS7A1633QDGNRQ1	HVSSOP	DGN	8	2500	367.0	367.0	38.0
TPS7A1650QDGNRQ1	HVSSOP	DGN	8	2500	367.0	367.0	38.0

DGN 8

PowerPAD™ HVSSOP - 1.1 mm max height

3 x 3, 0.65 mm pitch

SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4225482/B

A

5.05
4.75 TYP

PIN 1 INDEX AREA

8

6X 0.65

2X

1.95

5

8X 0.37
0.26

⊕ 0.1 Ⓜ C A B

1

3.1
2.9
NOTE 3

4

B

3.1
2.9
NOTE 4

C

◯ 0.1 C

SEATING PLANE

0.23
0.13

SEE DETAIL A

EXPOSED THERMAL PAD

4

5

1.92
1.66

9

1

8

1.60
1.34

0.25
GAGE PLANE

1.1 MAX

0.15
0.05

0°-8°

0.7
0.4
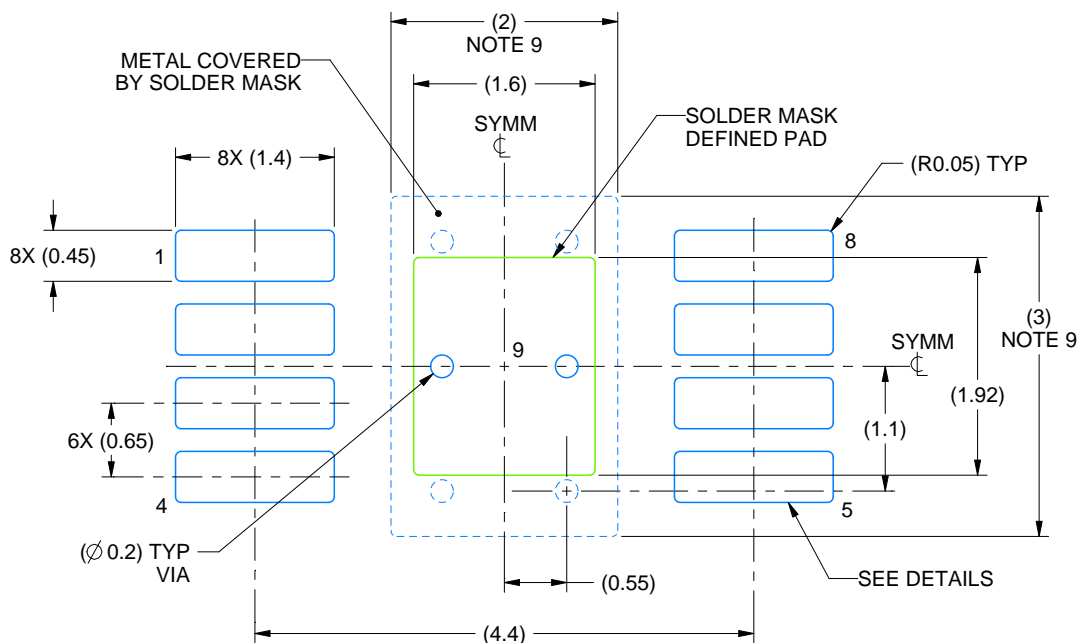
DETAIL A
TYPICAL

4218838/A   11/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
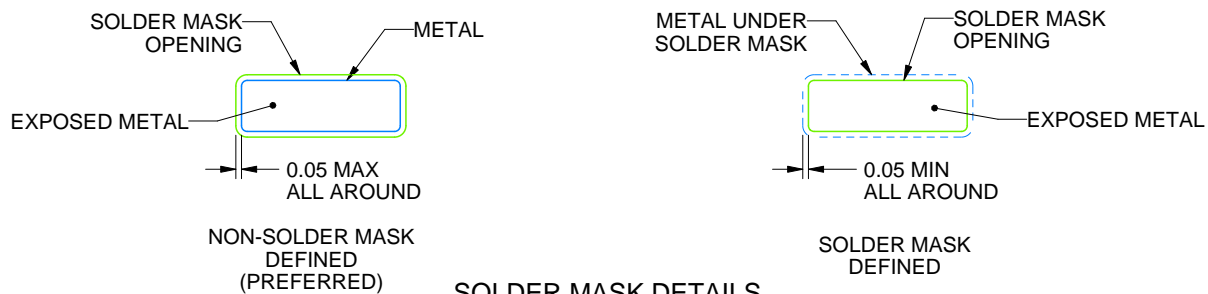5. Reference JEDEC registration MO-187.

METAL COVERED
BY SOLDER MASK

SOLDER MASK
DEFINED PAD

(2)
NOTE 9

(1.6)

SYMM

(R0.05) TYP

8X (1.4)

8X (0.45)   1

8

(3)
NOTE 9

9

SYMM

(1.92)

(1.1)

6X (0.65)

4

(Ø 0.2) TYP
VIA

5

(0.55)

SEE DETAILS

(4.4)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

0.05 MIN
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK DETAILS

SOLDER MASK
DEFINED

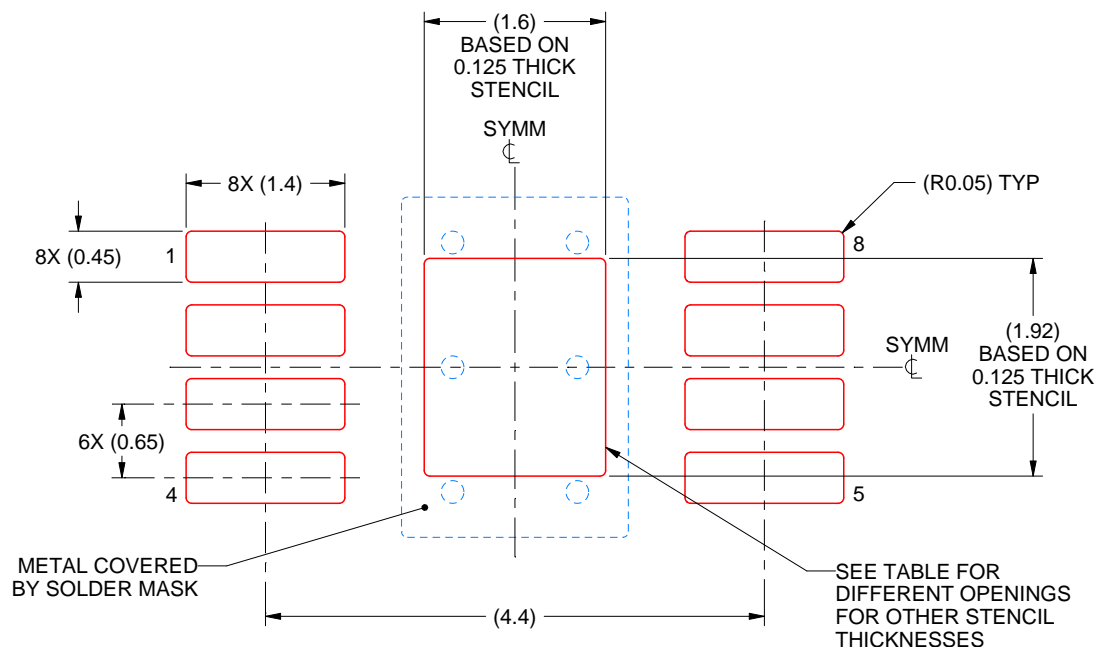4218838/A   11/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown
   on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

(1.6)
BASED ON
0.125 THICK
STENCIL

SYMM
¢

8X (1.4)

8X (0.45)   1

(R0.05) TYP

8

SYMM
¢

(1.92)
BASED ON
0.125 THICK
STENCIL

6X (0.65)

4

5

METAL COVERED
BY SOLDER MASK
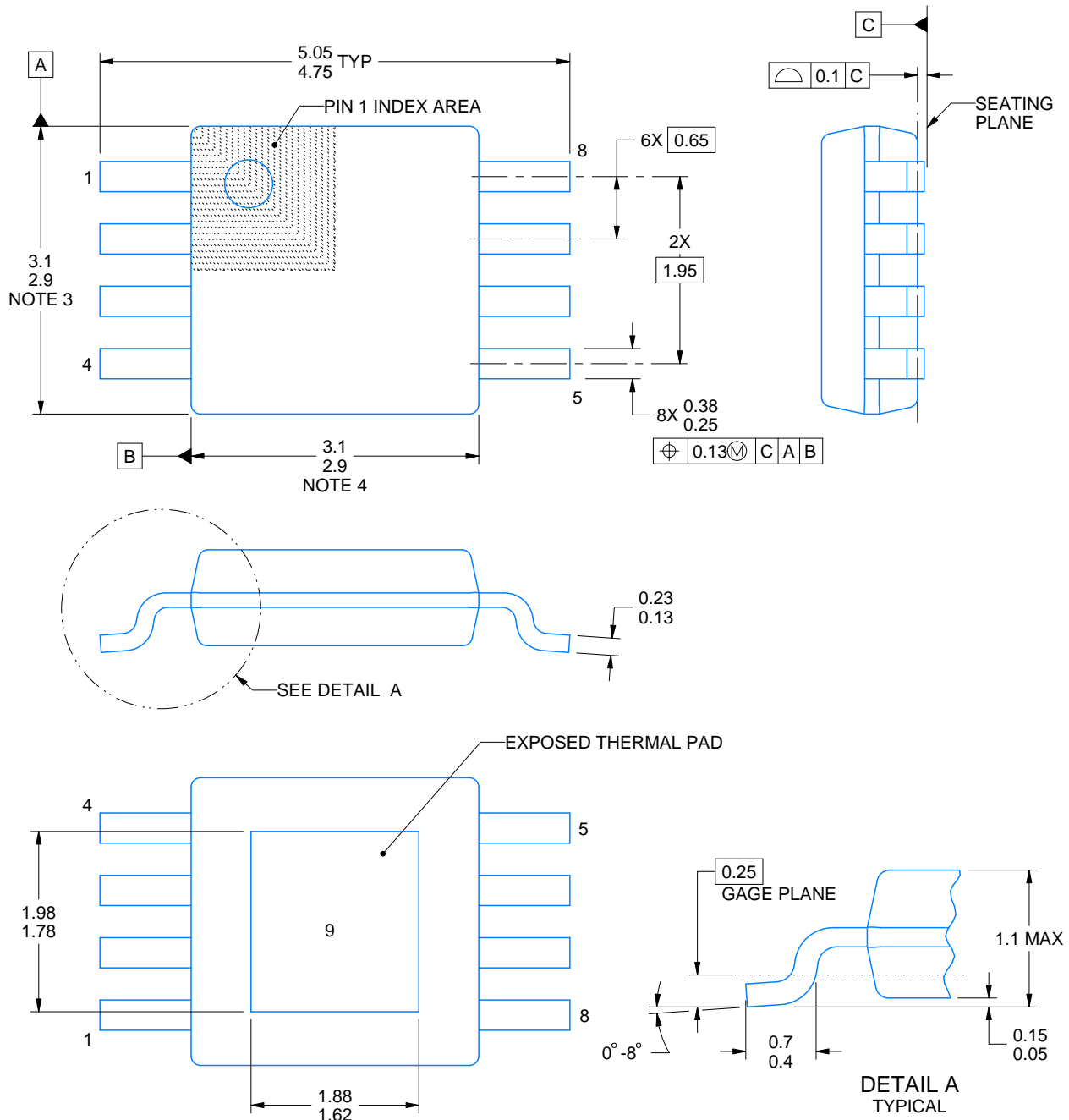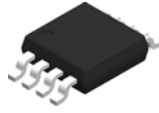
SEE TABLE FOR
DIFFERENT OPENINGS
FOR OTHER STENCIL
THICKNESSES

(4.4)

SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	1.79 X 2.15
0.125	1.60 X 1.92 (SHOWN)
0.15	1.46 X 1.75
0.175	1.35 X 1.62

4218838/A   11/2017

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

DGN0008B

SMALL OUTLINE PACKAGE

A

5.05
4.75 TYP

PIN 1 INDEX AREA

1

8

6X 0.65

2X 1.95

3.1
2.9
NOTE 3

4

5

8X 0.38
0.25

⊕ 0.13 Ⓜ C A B

B

3.1
2.9
NOTE 4

C

⌒ 0.1 C

SEATING PLANE

SEE DETAIL A

0.23
0.13

EXPOSED THERMAL PAD

4

5

1.98
1.78

9

1

8

1.88
1.62

0.25
GAGE PLANE

1.1 MAX

0°-8°

0.7
0.4

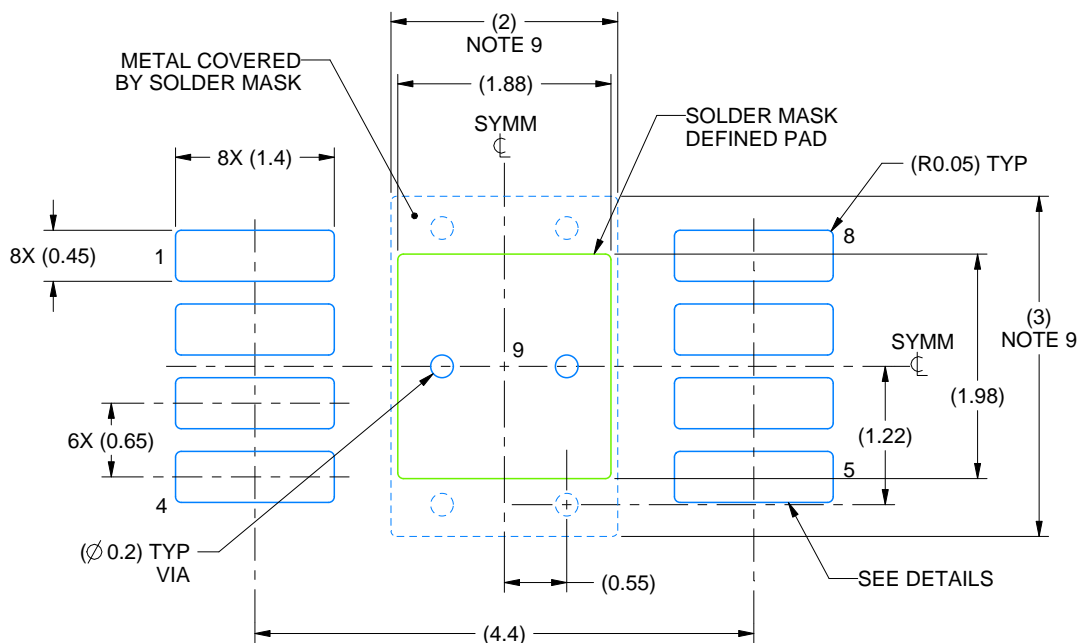0.15
0.05

DETAIL A
TYPICAL

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PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
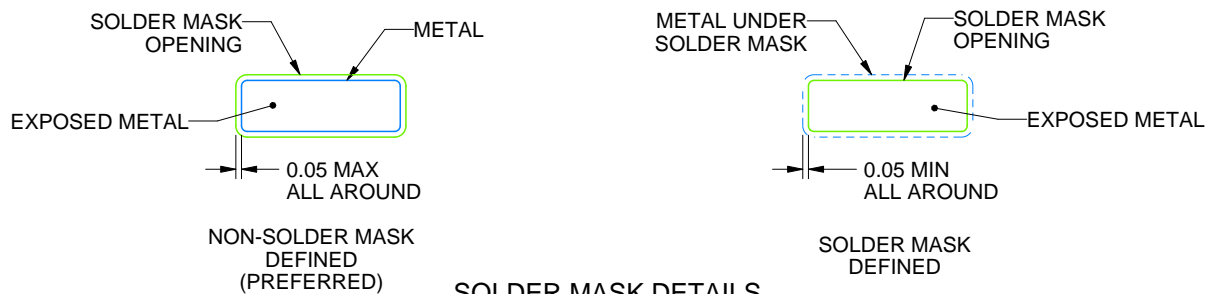5. Reference JEDEC registration MO-187.

TEXAS INSTRUMENTS
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(2)
NOTE 9

METAL COVERED
BY SOLDER MASK

(1.88)

SYMM

SOLDER MASK
DEFINED PAD

(R0.05) TYP

8X (1.4)

8

8X (0.45)   1

(3)
NOTE 9

SYMM

(1.98)

9

6X (0.65)

(1.22)

4

5

(∅ 0.2) TYP
VIA

(0.55)

SEE DETAILS

(4.4)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

0.05 MIN
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK DETAILS

SOLDER MASK
DEFINED

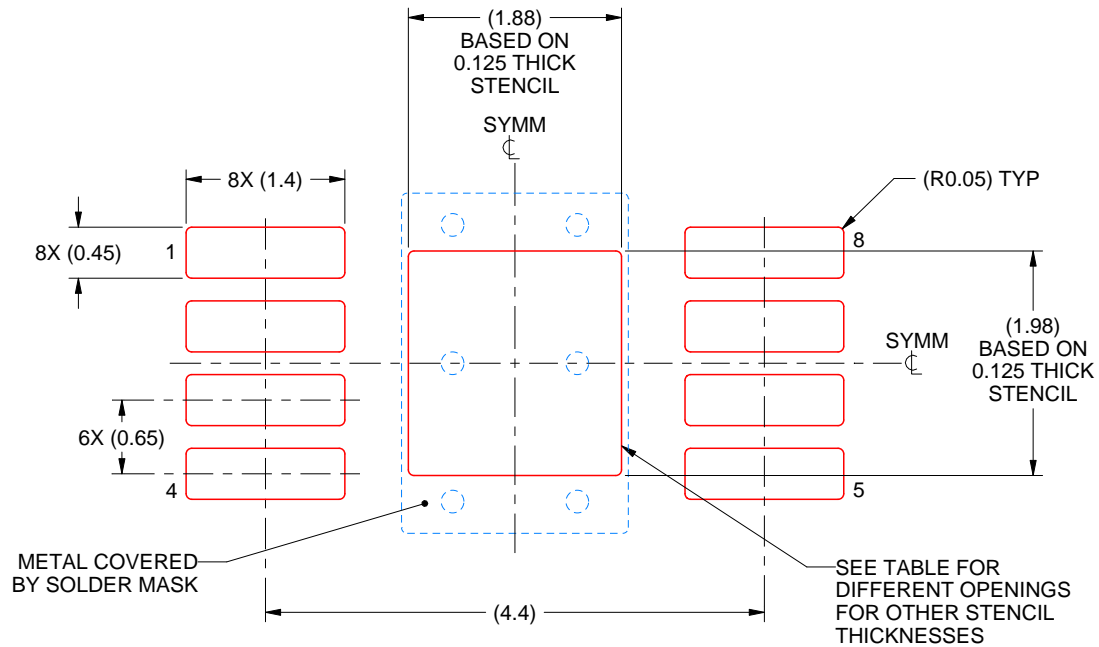4218837/B   03/2025

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown
   on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

(1.88)
BASED ON
0.125 THICK
STENCIL

SYMM
₵

8X (1.4)

(R0.05) TYP

8X (0.45)   1

8

SYMM
₵

(1.98)
BASED ON
0.125 THICK
STENCIL

6X (0.65)

4

5

METAL COVERED
BY SOLDER MASK

SEE TABLE FOR
DIFFERENT OPENINGS
FOR OTHER STENCIL
THICKNESSES

(4.4)

SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	2.10 X 2.21
0.125	1.88 X 1.98 (SHOWN)
0.15	1.72 X 1.81
0.175	1.59 X 1.67

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NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

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